# mail

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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







#### **FEATURES**

- Patent protected
- No opto feedback
- Optimised bipolar output voltages for IGBT/ SiC & MOSFET gate drives
- Configurable dual outputs for all gate drive applications:
  - +15V/-5V, +15V/-10V & +20V/-5V outputs
- Reinforced insulation to UL60950 recognised
- ANSI/AAMI ES60601-1 recognition pending
- Characterised dv/dt immunity 80kV/µs at 1.6kV
- Characterised partial discharge performance
- 5.7kVDC isolation test voltage 'Hi Pot Test'
- Ultra low coupling capacitance 15pF
- DC link voltage 3kVDC
- 5V, 12V & 24V input voltages
- 105°C operating temperature

#### **PRODUCT OVERVIEW**

Offering configurable dual output voltages of +15V/-10V, +20V/-5V and +15V/-5V, the MGJ6 series of DC-DC converters is ideal for powering 'high side' and 'low side' gate drive circuits for IGBTs, Silicon Carbide and MOSFETs in bridge circuits. A choice of asymmetric output voltages allows optimum drive levels for best system efficiency and EMI. The MGJ6 series is characterised for high isolation and dv/dt requirements commonly seen in bridge circuits used in motor drives and inverters. A disable/frequency synchronisation pin simplifies EMC filter design. The MGJ6 protection features include short circuit protection and overload protection.



MGJ6 SIP/DIP Series

#### 5.7kVDC Isolated 6W Gate Drive SIP/DIP DC/DC Converters

SELECTION GUIDE										
	Output 1					Output 2				
Order Code <sup>1</sup>	Input Voltage Range	Typical Application	Rated Output Voltage	Rated Output Current	Output Power	Rated Output Voltage	Rated Output Current	Output Power		
	V	See page 3	V	mA	W	V	mA	W		
MGJ6D051510DC	4.5 - 9	IGBT	+15	240	3.6	-10	240	2.4		
MGJ6D121510DC	9 - 18	IGBT	+15	240	3.6	-10	240	2.4		
MGJ6D241510DC	18 - 36	IGBT	+15	240	3.6	-10	240	2.4		
MGJ6D052005DC	4.5 - 9	SiC	+20	240	4.8	-5	240	1.2		
MGJ6D122005DC	9 - 18	SiC	+20	240	4.8	-5	240	1.2		
MGJ6D242005DC	18 - 36	SiC	+20	240	4.8	-5	240	1.2		
MGJ6D051505DC	4.5 - 9	MOSFET	+15	300	4.5	-5	300	1.5		
MGJ6D121505DC	9 - 18	MOSFET	+15	300	4.5	-5	300	1.5		
MGJ6D241505DC	18 - 36	MOSFET	+15	300	4.5	-5	300	1.5		
MGJ6D051510SC	4.5 - 9	IGBT	+15	240	3.6	-10	240	2.4		
MGJ6D121510SC	9 - 18	IGBT	+15	240	3.6	-10	240	2.4		
MGJ6D241510SC	18 - 36	IGBT	+15	240	3.6	-10	240	2.4		
MGJ6D052005SC	4.5 - 9	SiC	+20	240	4.8	-5	240	1.2		
MGJ6D122005SC	9 - 18	SiC	+20	240	4.8	-5	240	1.2		
MGJ6D242005SC	18 - 36	SiC	+20	240	4.8	-5	240	1.2		
MGJ6D051505SC	4.5 - 9	MOSFET	+15	300	4.5	-5	300	1.5		
MGJ6D121505SC	9 - 18	MOSFET	+15	300	4.5	-5	300	1.5		
MGJ6D241505SC	18 - 36	MOSFET	+15	300	4.5	-5	300	1.5		

1. Components are supplied in tray packaging, please refer to package specification section for more details. All specifications typical at T\_=25°C, nominal input voltage and rated output current unless otherwise specified.

# **MGJ6 SIP/DIP Series**

5.7kVDC Isolated 6W Gate Drive SIP/DIP DC/DC Converters

SELECTION GUIDE (	Continued	)									
			Output 1				Output 2				
Order Code <sup>1</sup>	Input Voltage Range	Typical Application	Load Regulation (Typ)	Load Regulation (Max)	Ripple & Noise $(Typ)^2$	Ripple & Noise (Max) <sup>2</sup>	Load Regulation (Typ)	Load Regulation (Max)	Ripple & Noise $(Typ)^2$	Ripple & Noise (Max) <sup>2</sup>	
	V	See page 3	0	6	mV	р-р	9	%		р-р	
MGJ6D051510DC	4.5 - 9	IGBT	5	10	150	200	5	10	70	110	
MGJ6D121510DC	9 - 18	IGBT	5	10	150	200	5	10	70	110	
MGJ6D241510DC	18 - 36	IGBT	5	10	150	200	5	10	70	110	
MGJ6D052005DC	4.5 - 9	SiC	5	10	150	200	5	10	70	110	
MGJ6D122005DC	9 - 18	SiC	5	10	150	200	5	10	70	110	
MGJ6D242005DC	18 - 36	SiC	5	10	150	200	5	10	70	110	
MGJ6D051505DC	4.5 - 9	MOSFET	5	10	150	200	5	10	70	110	
MGJ6D121505DC	9 - 18	MOSFET	5	10	150	200	5	10	70	110	
MGJ6D241505DC	18 - 36	MOSFET	5	10	150	200	5	10	70	110	
MGJ6D051510SC	4.5 - 9	IGBT	5	10	150	200	5	10	70	110	
MGJ6D121510SC	9 - 18	IGBT	5	10	150	200	5	10	70	110	
MGJ6D241510SC	18 - 36	IGBT	5	10	150	200	5	10	70	110	
MGJ6D052005SC	4.5 - 9	SiC	5	10	150	200	5	10	70	110	
MGJ6D122005SC	9 - 18	SiC	5	10	150	200	5	10	70	110	
MGJ6D242005SC	18 - 36	SiC	5	10	150	200	5	10	70	110	
MGJ6D051505SC	4.5 - 9	MOSFET	5	10	150	200	5	10	70	110	
MGJ6D121505SC	9 - 18	MOSFET	5	10	150	200	5	10	70	110	
MGJ6D241505SC	18 - 36	MOSFET	5	10	150	200	5	10	70	110	

1. Components are supplied in tray packaging, please refer to package specification section for more details.

2. See ripple & noise test method.

# **MGJ6 SIP/DIP Series**

5.7kVDC Isolated 6W Gate Drive SIP/DIP DC/DC Converters

SELECTION GUIDE (C	ontinued)						
Order Code <sup>1</sup>	Nominal Input Voltage	Input Current at Rated Load	Efficiency (Min)	Efficiency (Typ)	Isolation Capacitance	LM MIL 217	Telecordia
	V	mA	0	6	pF	kl	lrs
MGJ6D051510DC	5	1500	77.5	80	15	627	12,576
MGJ6D121510DC	12	620	77.5	80	15	789	19,546
MGJ6D241510DC	24	300	80	82	15	784	19,570
MGJ6D052005DC	5	1500	77.5	80	15	627	12,576
MGJ6D122005DC	12	620	77.5	80	15	789	19,546
MGJ6D242005DC	24	300	80	82	15	784	19,570
MGJ6D051505DC	5	1500	77.5	80	15	627	12,576
MGJ6D121505DC	12	620	77.5	80	15	789	19,546
MGJ6D241505DC	24	300	80	82	15	784	19,570
MGJ6D051510SC	5	1500	74	77.5	15	492	13,469
MGJ6D121510SC	12	620	78	80.5	15	789	19,546
MGJ6D241510SC	24	300	80	82	15	784	19,570
MGJ6D052005SC	5	1500	74	77.5	15	492	13,469
MGJ6D122005SC	12	620	78	80.5	15	789	19,546
MGJ6D242005SC	24	300	80	82	15	784	19,570
MGJ6D051505SC	5	1500	74	77.5	15	492	13,469
MGJ6D121505SC	12	620	78	80.5	15	789	19,546
MGJ6D241505SC	24	300	80	82	15	784	19,570

1. Components are supplied in tray packaging, please refer to package specification section for more details.

2.Calculated using MIL-HDBK-217 FN2 and Telcordia SR-332 calculation model with nominal input voltage at full load.

# **MGJ6 SIP/DIP Series**

5.7kVDC Isolated 6W Gate Drive SIP/DIP DC/DC Converters

INPUT CHARACTERISTICS Parameter	Conditions	Min.	Тур.	Max.	Units
raiaiiicici		4.5	1yp. 5	9	Unit
Voltogo rongo	5V input types				v
Voltage range	12V input types	9	12	18	V
	24V input types	18	24	36	
	Turn on threshold MGJ6D05		4.1		
	Turn off threshold MGJ6D05		3.0		
Under voltage lock out	Turn on threshold MGJ6D12		8.1		v
ondor ronago roon out	Turn off threshold MGJ6D12		7.5		
	Turn on threshold MGJ6D24		16.7		
	Turn off threshold MGJ6D24		16.3		
	5V input types		40		
Input ripple current	12V input types		40		mA
	24V input types		24		р-р
OUTPUT CHARACTERISTICS					
Parameter	Conditions	Min.	Тур.	Max.	Units
Minimum load	Below 10% load, 5V and 15V outputs are clamped to 6V and 17V respectively	10			%
	Output 1		±3		%
Voltage set point accuracy	Output 2		±5		%
Line regulation	Low line to high line			2	%
				15	%
Total Regulation					/0
Total Regulation	Peak deviation (50-100% & 100-50% load swing)				
Total Regulation Transient response	Peak deviation (50-100% & 100-50% load swing) Settling time				%V <sub>ou</sub>
Transient response	Peak deviation (50-100% & 100-50% load swing) Settling time				
Transient response GENERAL CHARACTERISTICS	Settling time		Tur		%V <sub>ou</sub> ms
Transient response GENERAL CHARACTERISTICS Parameter		Min.	Тур.	Max.	%V <sub>ou</sub> ms Units
Transient response GENERAL CHARACTERISTICS	Settling time	Min.	Тур. 100		%V <sub>ou</sub>
Transient response GENERAL CHARACTERISTICS Parameter Switching frequency	Settling time	Min.			%V <sub>ou</sub> ms Units
Transient response GENERAL CHARACTERISTICS Parameter	Settling time	Min.			%V <sub>ou</sub> ms Units kHz
Transient response GENERAL CHARACTERISTICS Parameter Switching frequency ISOLATION CHARACTERISTICS Parameter	Settling time Conditions		100	Max.	%V <sub>ou</sub> ms Units kHz Units
Transient response GENERAL CHARACTERISTICS Parameter Switching frequency ISOLATION CHARACTERISTICS	Settling time Conditions Conditions	Min.	100	Max.	%V <sub>ou</sub> ms Units kHz Units
Transient response  GENERAL CHARACTERISTICS  Parameter  Switching frequency  ISOLATION CHARACTERISTICS  Parameter	Settling time Conditions Conditions Production tested for 1 second	Min. 5700	100	Max.	%V <sub>ou</sub> ms Units
Transient response  GENERAL CHARACTERISTICS Parameter Switching frequency  ISOLATION CHARACTERISTICS Parameter Isolation test voltage	Settling time Conditions Conditions Production tested for 1 second Qualification tested for 1 minute	Min. 5700 5700	100	Max.	%V <sub>ou</sub> ms Units kHz Units VDC
Transient response  GENERAL CHARACTERISTICS  Parameter Switching frequency  ISOLATION CHARACTERISTICS Parameter Isolation test voltage Resistance Continuous barrier withstand voltage	Settling time         Conditions         Conditions         Production tested for 1 second         Qualification tested for 1 minute         Viso = 1kVDC	Min. 5700 5700	100	Max. Max.	%V <sub>ou</sub> ms Units kHz Units VDC GΩ
Transient response  GENERAL CHARACTERISTICS Parameter Switching frequency  ISOLATION CHARACTERISTICS Parameter Isolation test voltage Resistance	Settling time         Conditions         Conditions         Production tested for 1 second         Qualification tested for 1 minute         Viso = 1kVDC         Non-safety barrier application	Min. 5700 5700	100	Max. Max.	%V <sub>ou</sub> ms Units kHz Units VDC GΩ
Transient response  GENERAL CHARACTERISTICS  Parameter Switching frequency  ISOLATION CHARACTERISTICS Parameter Isolation test voltage Resistance Continuous barrier withstand voltage  ABSOLUTE MAXIMUM RATINGS	Settling time Conditions Conditions Production tested for 1 second Qualification tested for 1 minute Viso = 1kVDC Non-safety barrier application Cc	Min. 5700 5700 100	100	Max. Max.	%V <sub>o</sub> , ms Units kHz Units VDC
Transient response  GENERAL CHARACTERISTICS  Parameter Switching frequency  ISOLATION CHARACTERISTICS  Parameter Isolation test voltage Resistance Continuous barrier withstand voltage  ABSOLUTE MAXIMUM RATINGS Short-circuit protection	Settling time Conditions Conditions Production tested for 1 second Qualification tested for 1 minute Viso = 1kVDC Non-safety barrier application Cc	Min. 5700 5700 100 ntinuous 50°C	100	Max. Max.	%V <sub>o</sub> u ms Units kHz Units VDC
Transient response  GENERAL CHARACTERISTICS  Parameter Switching frequency  ISOLATION CHARACTERISTICS  Parameter Isolation test voltage Resistance Continuous barrier withstand voltage  ABSOLUTE MAXIMUM RATINGS Short-circuit protection Lead temperature 1.0mm from case for 10 secon	Settling time         Conditions         Conditions         Production tested for 1 second         Qualification tested for 1 minute         Viso = 1kVDC         Non-safety barrier application         Code (to JEDEC JESD22-B106 ISS C)	Min. 5700 5700 100 000 00°C 2V	100	Max. Max.	%V <sub>ou</sub> ms Units kHz Units VDC GΩ
Transient response  GENERAL CHARACTERISTICS  Parameter Switching frequency  ISOLATION CHARACTERISTICS Parameter Isolation test voltage Resistance Continuous barrier withstand voltage  ABSOLUTE MAXIMUM RATINGS Short-circuit protection Lead temperature 1.0mm from case for 10 secon Input voltage, MGJ6 5V input types	Settling time         Conditions         Conditions         Production tested for 1 second         Qualification tested for 1 minute         Viso = 1kVDC         Non-safety barrier application         Code (to JEDEC JESD22-B106 ISS C)         12	Min. 5700 5700 100 000 00°C 2V 0V	100	Max. Max.	%V <sub>ou</sub> ms Units kHz Units VDC GΩ
Transient response  GENERAL CHARACTERISTICS  Parameter Switching frequency  ISOLATION CHARACTERISTICS Parameter Isolation test voltage Resistance Continuous barrier withstand voltage  ABSOLUTE MAXIMUM RATINGS Short-circuit protection Lead temperature 1.0mm from case for 10 secon Input voltage, MGJ6 5V input types Input voltage, MGJ6 12V input types Input voltage, MGJ6 24V input types	Settling time         Conditions         Conditions         Production tested for 1 second         Qualification tested for 1 minute         Viso = 1kVDC         Non-safety barrier application         ds (to JEDEC JESD22-B106 ISS C)         12         20	Min. 5700 5700 100 000 00°C 2V 0V	100	Max. Max.	%V <sub>ou</sub> ms Units kHz Units VDC GΩ
Transient response  GENERAL CHARACTERISTICS  Parameter Switching frequency  ISOLATION CHARACTERISTICS Parameter Isolation test voltage Resistance Continuous barrier withstand voltage  ABSOLUTE MAXIMUM RATINGS Short-circuit protection Lead temperature 1.0mm from case for 10 secon Input voltage, MGJ6 5V input types Input voltage, MGJ6 12V input types	Settling time         Conditions         Conditions         Production tested for 1 second         Qualification tested for 1 minute         Viso = 1kVDC         Non-safety barrier application         ds (to JEDEC JESD22-B106 ISS C)         12         20	Min. 5700 5700 100 000 00°C 2V 0V	100 Typ.	Max. Max.	%V <sub>o</sub> u ms Units kHz Units VDC
Transient response  GENERAL CHARACTERISTICS  Parameter Switching frequency  ISOLATION CHARACTERISTICS  Parameter Isolation test voltage Resistance Continuous barrier withstand voltage  ABSOLUTE MAXIMUM RATINGS Short-circuit protection Lead temperature 1.0mm from case for 10 secon Input voltage, MGJ6 5V input types Input voltage, MGJ6 12V input types Input voltage, MGJ6 24V input types TEMPERATURE CHARACTERISTICS Parameter	Settling time Conditions Conditions Production tested for 1 second Qualification tested for 1 minute Viso = 1kVDC Non-safety barrier application Ccc ds (to JEDEC JESD22-B106 ISS C) 12 Ccc 40	Min. 5700 5700 100 ontinuous 50°C 2V 0V	100	Max. Max. 3000	%V <sub>o</sub> , ms Unit: kHz Unit: VDC GΩ VDC
Transient response  GENERAL CHARACTERISTICS  Parameter Switching frequency  ISOLATION CHARACTERISTICS  Parameter Isolation test voltage Resistance Continuous barrier withstand voltage  ABSOLUTE MAXIMUM RATINGS Short-circuit protection Lead temperature 1.0mm from case for 10 secon Input voltage, MGJ6 5V input types Input voltage, MGJ6 12V input types Input voltage, MGJ6 24V input types TEMPERATURE CHARACTERISTICS	Settling time Conditions Conditions Conditions Production tested for 1 second Qualification tested for 1 minute Viso = 1kVDC Non-safety barrier application Cods (to JEDEC JESD22-B106 ISS C)	Min. 5700 5700 100 000°C 2V 0V 0V 0V 0V	100 Typ.	Max. Max. 3000	%V <sub>o</sub> , ms Unit: kHz Unit: VDC GΩ VDC



This series is compatible with RoHS soldering systems with a peak wave solder temperature of 260°C for 10 seconds. The pin termination finish on this product series is Tin with Nickel Preplate. The series is backward compatible with Sn/Pb soldering systems.

# **MGJ6 SIP/DIP Series**

5.7kVDC Isolated 6W Gate Drive SIP/DIP DC/DC Converters

#### **APPLICATION NOTES**

#### Start-up times

Typical start up times for this series, with no additional output capacitance are:

D 111	Start-up times		
Part No.	ms		
MGJ6D051510DC	15		
MGJ6D121510DC	15		
MGJ6D241510DC	15		
MGJ6D052005DC	15		
MGJ6D122005DC	15		
MGJ6D242005DC	15		
MGJ6D051505DC	15		
MGJ6D121505DC	15		
MGJ6D241505DC	15		
MGJ6D051510SC	15		
MGJ6D121510SC	15		
MGJ6D241510SC	15		
MGJ6D052005SC	15		
MGJ6D122005SC	15		
MGJ6D242005SC	15		
MGJ6D051505SC	15		
MGJ6D121505SC	15		
MGJ6D241505SC	15		

Output capacitance must not exceed:

Output Voltage	Maximum output capacitance
V	μF
-5	470
-10	220
15	220
20	150

#### Disable/Frequency synchronisation

Please refer to application notes for further information.

		Min	Тур	Max	Units
	Pull Down Current		0.5		mA
Disable/Synch <sup>1</sup>	Input High	2		5	V
	Input Low	0		0.8	V
Synchronisation	Frequency Range	90	100	110	kHz
Synchionisation	Duty Cycle	25		75	%

The Disable/Synchronization pin has three modes:

1. When a dc logic low voltage is applied to this pin the MGJ6 is disabled and enters a low quiescent current sleep mode.

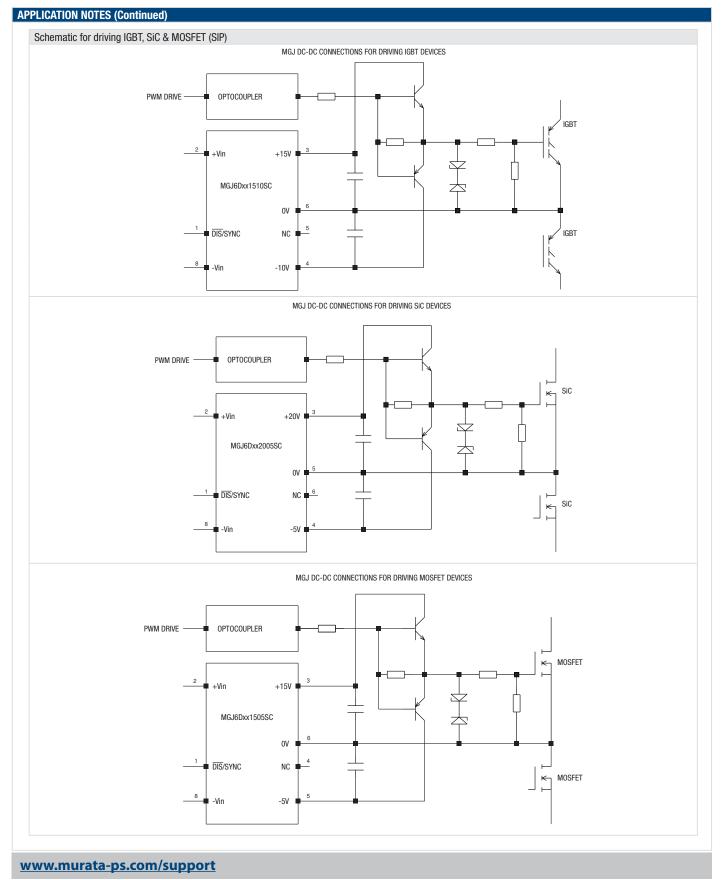
2. When this pin is left floating or a dc logic high (CMOS/TTL compatible) voltage is applied the MGJ6 is enabled and operates at the programmed frequency of 100kHz. 3. When a square wave of between 90kHz and 110kHz is applied to this pin, the switcher operates at the same frequency as the square wave. The falling edge of the square wave corresponds to the start of the switching cycle. If the signal is slower than 25Hz, it will be interpreted as enabling and disabling the part. If the MGJ6 is disabled, it must be disabled for 7 clock cycles before being re-enabled.

# **MGJ6 SIP/DIP Series**

configurations for p	power switch	nes			
Terminal	Pin (SIP)	Pin (DIP)	IGBT	SIC	MOSFET
15V Output	3	5	+15V 0.24A	+20V 0.24A	+15V 0.3A
15V Return 5VA Output	6	4	OV	No connection	OV
5VA Return 5VB Output	5	3	No connection	OV	-5V 0.3A
5VB Return	4	2	-10V 0.24A	-5V 0.24A	No connection

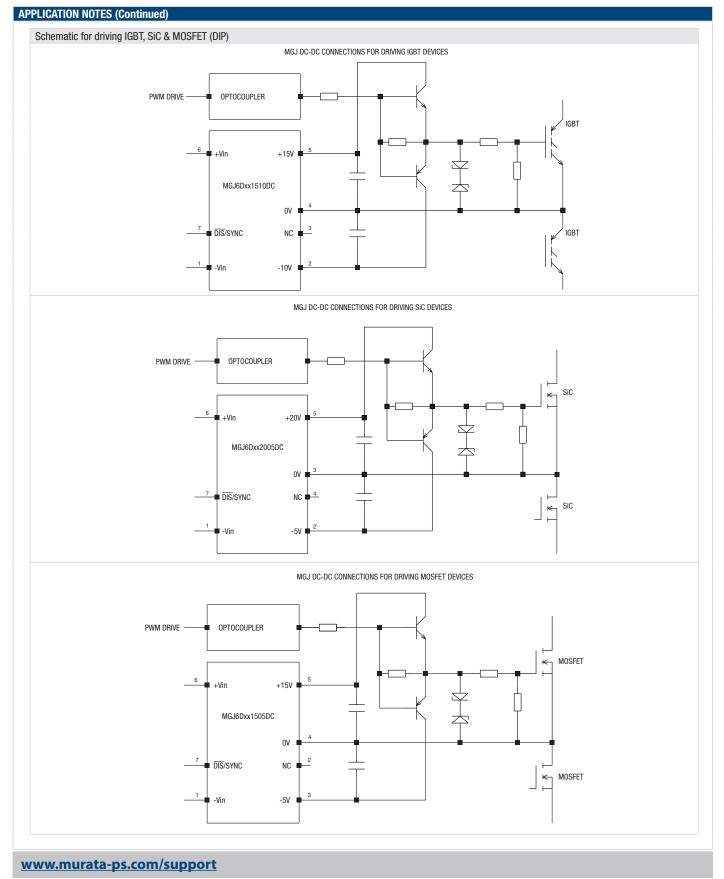
# **MGJ6 SIP/DIP Series**

5.7kVDC Isolated 6W Gate Drive SIP/DIP DC/DC Converters



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# **MGJ6 SIP/DIP Series**



## **MGJ6 SIP/DIP Series**

#### 5.7kVDC Isolated 6W Gate Drive SIP/DIP DC/DC Converters

#### **TECHNICAL NOTES**

#### **ISOLATION VOLTAGE**

'Hi Pot Test', 'Flash Tested', 'Withstand Voltage', 'Proof Voltage', 'Dielectric Withstand Voltage' & 'Isolation Test Voltage' are all terms that relate to the same thing, a test voltage, applied for a specified time, across a component designed to provide electrical isolation, to verify the integrity of that isolation.

Murata Power Solutions MGJ6 series of DC/DC converters are all 100% production tested at 5.7kVDC for 1 second and have been qualification tested at 5.7kVDC for 1 minute.

A question commonly asked is, "What is the continuous voltage that can be applied across the part in normal operation?"

When the insulation in the MGJ6 series is not used as a safety barrier , i.e. provides functional isolation only, continuous or switched voltages across the barrier up to 3kV are sustainable. Long term reliability testing at these voltages continues. Peak Inception voltages measured were in excess of 3.5kV when testing for partial discharge in accordance with IEC 60270. Please contact Murata for further information.

The MGJ6 series has been recognised by Underwriters Laboratory to 250 Vrms Reinforced Insulation, please see safety approval section below.

#### **REPEATED HIGH-VOLTAGE ISOLATION TESTING**

It is well known that repeated high-voltage isolation testing of a barrier component can actually degrade isolation capability, to a lesser or greater degree depending on materials, construction and environment. We therefore strongly advise against repeated high voltage isolation testing, but if it is absolutely required, that the voltage be reduced by 20% from specified test voltage.

#### SAFETY APPROVAL

#### ANSI/AAMI ES60601-1

The MGJ6 series is pending recognition ANSI/AAMI ES60601-1 and provides 2 MOPP (Means Of Patient Protection) based upon a working voltage of 250 Vrms max., between Primary and Secondary.

#### UL 60950

The MGJ6 series has been recognised by Underwriters Laboratory (UL) to UL 60950 for reinforced insulation to a working voltage of 250Vrms with a maximum measured product operating temperature of 130°C.

Creepage and clearance 8mm.

#### FUSING

The MGJ6 Series of converters are not internally fused so to meet the requirements of UL an anti-surge input line fuse should always be used with ratings as defined below. Input Voltage, 5V 4A Input Voltage, 12V 2A Input Voltage, 15V 1A All fuses should be UL recognized, 125V rated.

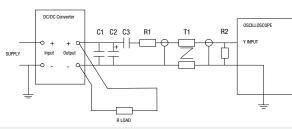
#### CHARACTERISATION TEST METHODS

#### **Ripple & Noise Characterisation Method**

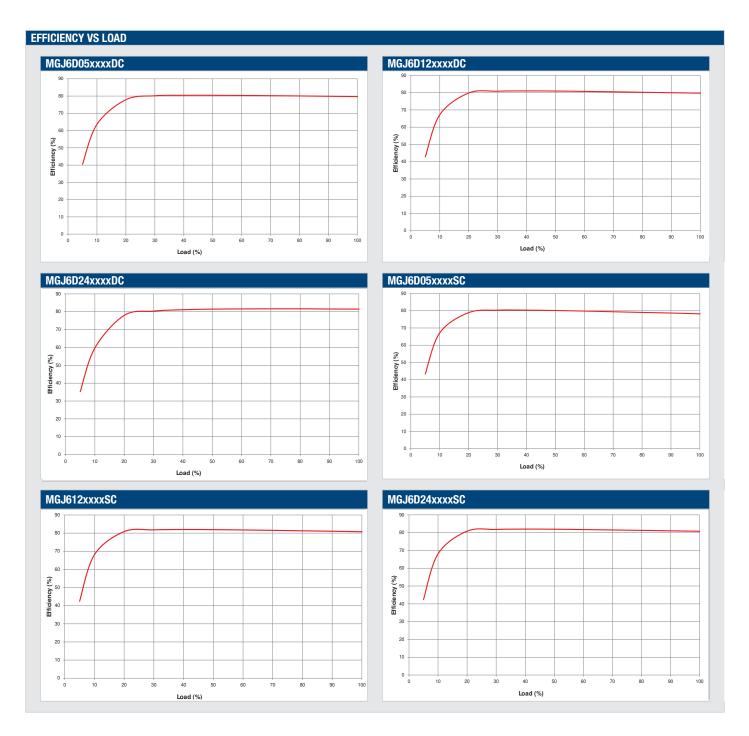
Ripple and noise measurements are performed with the following test configuration.

C1	1µF X7R multilayer ceramic capacitor, voltage rating to be a minimum of 3 times the output voltage of the DC/DC converter
C2	$10\mu$ F tantalum capacitor, voltage rating to be a minimum of 1.5 times the output voltage of the DC/DC converter with an ESR of less than $100 \text{ m}\Omega$ at $100 \text{ kHz}$
C3	100nF multilayer ceramic capacitor, general purpose
R1	450Ω resistor, carbon film, $\pm$ 1% tolerance
R2	50Ω BNC termination
T1	3T of the coax cable through a ferrite toroid
RLOAD	Resistive load to the maximum power rating of the DC/DC converter. Connections should be made via twisted wires
Measured va	lues are multiplied by 10 to obtain the specified values.

**Differential Mode Noise Test Schematic** 



# **MGJ6 SIP/DIP Series**

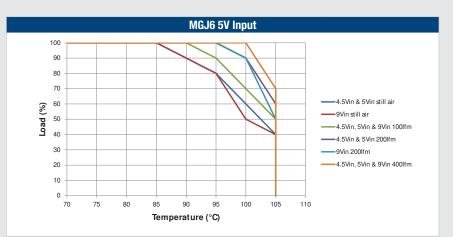


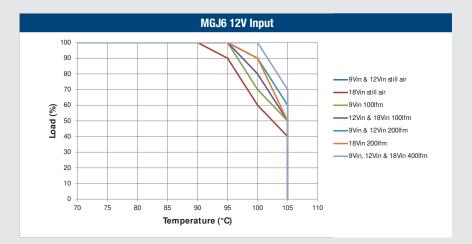
## **MGJ6 SIP/DIP Series**

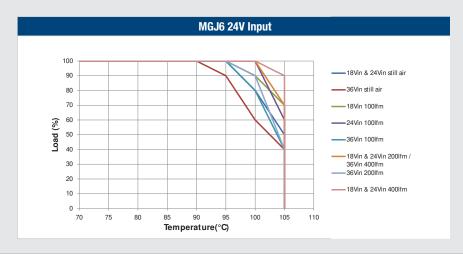
5.7kVDC Isolated 6W Gate Drive SIP/DIP DC/DC Converters

#### **DERATING GRAPHS**

Derating curves are based on IPC-9592. With no derating some components may be operating at the manufacturers maximum temperature ratings.







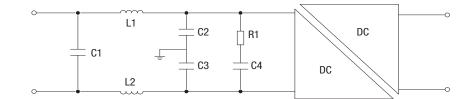
## **MGJ6 SIP/DIP Series**

#### 5.7kVDC Isolated 6W Gate Drive SIP/DIP DC/DC Converters

#### **EMC FILTERING AND SPECTRA**

#### FILTERING

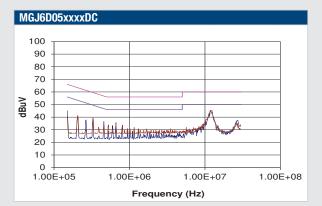
The following filter circuit and filter table shows the input filters typically required to meet EN 55022 Curve B, Quasi-Peak EMC limit, as shown in the following plots. The following plots show positive and negative quasi peak and CISPR22 Average Limit B (purple line) and Quasi Peak Limit B (pink line) adherence limits.

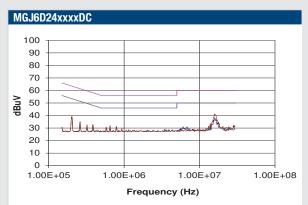


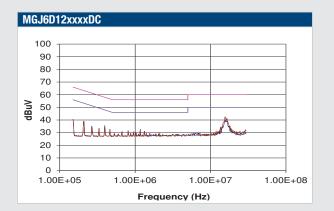
#### C1, C2 & C3 Polyester or ceramic capacitor

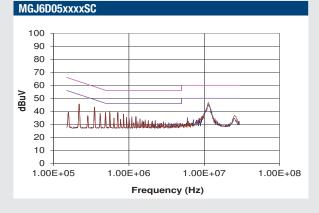
C4 Electrolytic capacitor (note R1 could be omitted if C4 has ESR >= R1)

TO MEET CURVE B						
Part Number	C1	L1&2	Through Hole	C2&3	R1	C4
MGJ6D05XXXXXC	3.3uF	10uH	47100SC	10nF	<b>500Μ</b> Ω	470uF
MGJ6D05XXXXXC	3.3uF	10uH	47100SC	10nF	<b>500Μ</b> Ω	470uF
MGJ6D05XXXXXC	3.3uF	10uH	47100SC	10nF	<b>500Μ</b> Ω	470uF



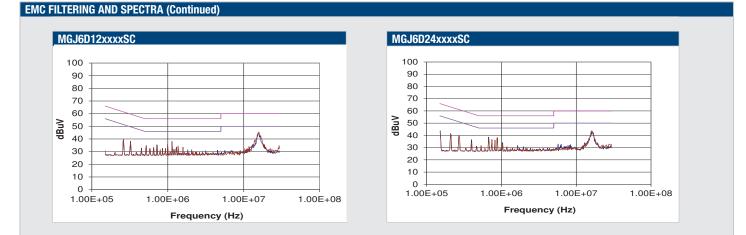






# **MGJ6 SIP/DIP Series**

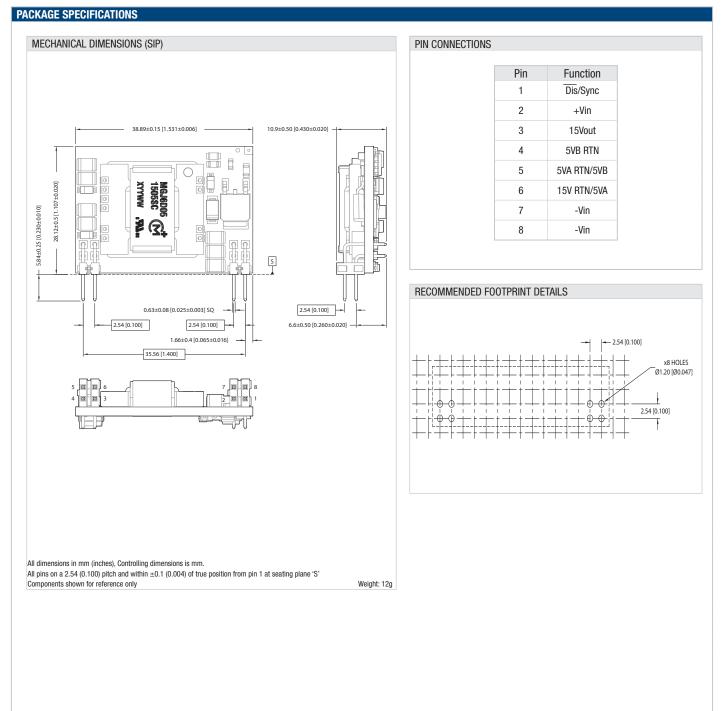
5.7kVDC Isolated 6W Gate Drive SIP/DIP DC/DC Converters



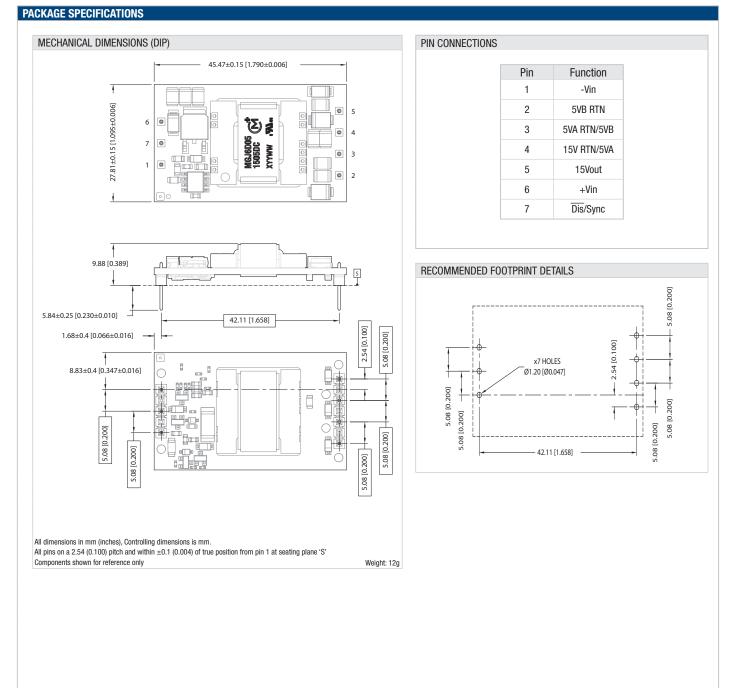
### www.murata-ps.com/support

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# **MGJ6 SIP/DIP Series**

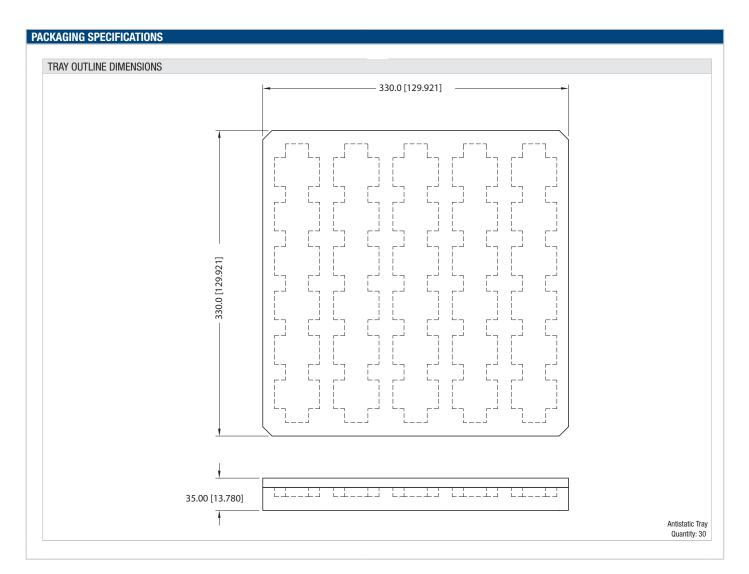


# **MGJ6 SIP/DIP Series**



# **MGJ6 SIP/DIP Series**

5.7kVDC Isolated 6W Gate Drive SIP/DIP DC/DC Converters



Murata Power Solutions, Inc. 11 Cabot Boulevard, Mansfield, MA 02048-1151 U.S.A. ISO 9001 and 14001 REGISTERED



and the Life and Safety Critical Application Sales Policy: Refer to: http://www.murata-ps.com/requirements/

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